

LMC6022 Low Power CMOS Dual Operational Amplifier

Check for Samples: [LMC6022](#)

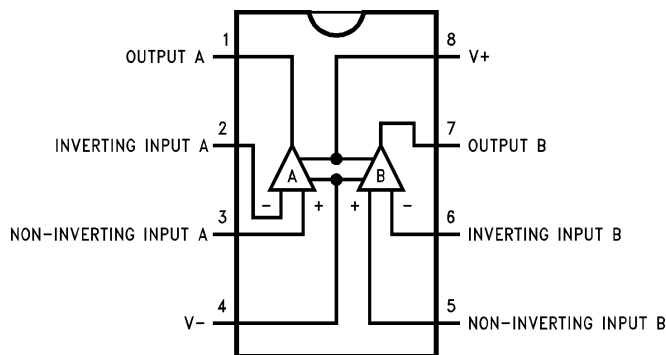
FEATURES

- Specified for 100 k Ω and 5 k Ω Loads
- High Voltage Gain: 120 dB
- Low Offset Voltage Drift: 2.5 $\mu\text{V}/^\circ\text{C}$
- Ultra Low Input Bias Current: 40 fA
- Input Common-Mode Range Includes V^-
- Operating Range from +5V to +15V Supply
- Low Distortion: 0.01% at 1 kHz
- Slew Rate: 0.11 V/ μs
- Micropower Operation: 0.5 mW

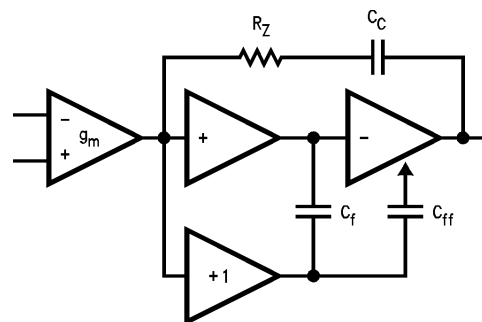
APPLICATIONS

- High-Impedance Buffer or Preamplifier
- Current-to-Voltage Converter
- Long-Term Integrator
- Sample-and-Hold Circuit
- Peak Detector
- Medical Instrumentation
- Industrial Controls

Connection Diagram



**Figure 1. 8-Pin SOIC
Top View**



**Figure 2. LMC6022 Circuit Topology
(Each Amplifier)**



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Differential Input Voltage	±Supply Voltage
Supply Voltage ($V^+ - V^-$)	16V
Lead Temperature (Soldering, 10 sec.)	260°C
Storage Temperature Range	-65°C to +150°C
Junction Temperature	150°C
ESD Tolerance ⁽²⁾	1000V
Voltage at Output/Input Pin	(V^+) +0.3V, (V^-) -0.3V
Current at Output Pin	±18 mA
Current at Power Supply Pin	35 mA
Power Dissipation	See ⁽³⁾
Current at Input Pin	±5 mA
Output Short Circuit to V^-	See ⁽⁴⁾
Output Short Circuit to V^+	See ⁽⁵⁾

- (1) Absolute Maximum Ratings indicate limits beyond which damage to component may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed.
- (2) Human body model, 100 pF discharged through a 1.5 kΩ resistor.
- (3) The maximum power dissipation is a function of $T_{J(max)}$, θ_{JA} and T_A . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(max)} - T_A)/\theta_{JA}$.
- (4) Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature and/or multiple Op Amp shorts can result in exceeding the maximum allowed junction temperature of 150°C. Output currents in excess of ±30 mA over long term may adversely affect reliability.
- (5) Do not connect output to V^+ when V^+ is greater than 13V or reliability may be adversely affected.

OPERATING RATINGS

Temperature Range	-40°C ≤ T_J ≤ +85°C
Supply Voltage Range	4.75V to 15.5V
Power Dissipation	See ⁽¹⁾
Thermal Resistance (θ_{JA}) ⁽²⁾	8-Pin SOIC 165°C/W

- (1) For operating at elevated temperatures the device must be derated based on the thermal resistance θ_{JA} with $P_D = (T_J - T_A)/\theta_{JA}$.
- (2) All numbers apply for packages soldered directly into a PC board.

DC ELECTRICAL CHARACTERISTICS

The following specifications apply for $V^+ = 5V$, $V^- = 0V$, $V_{CM} = 1.5V$, $V_O = 2.5V$, and $R_L = 1M$ unless otherwise noted.

Boldface limits apply at the temperature extremes; all other limits $T_J = 25^\circ\text{C}$.

Symbol	Parameter	Conditions	Typical ⁽¹⁾	LMC6022I Limit ⁽²⁾	Units
V_{OS}	Input Offset Voltage		1	9 11	mV max
$\Delta V_{OS}/\Delta T$	Input Offset Voltage Average Drift		2.5		$\mu\text{V}/^\circ\text{C}$
I_B	Input Bias Current		0.04	200	pA max
I_{OS}	Input Offset Current		0.01	100	pA max
R_{IN}	Input Resistance		>1		TeraΩ

- (1) Typical values represent the most likely parametric norm.
- (2) All limits are guaranteed by testing or correlation.

DC ELECTRICAL CHARACTERISTICS (continued)

The following specifications apply for $V^+ = 5V$, $V^- = 0V$, $V_{CM} = 1.5V$, $V_O = 2.5V$, and $R_L = 1M$ unless otherwise noted.

Boldface limits apply at the temperature extremes; all other limits $T_J = 25^\circ C$.

Symbol	Parameter	Conditions	Typical ⁽¹⁾	LMC6022I Limit ⁽²⁾	Units
CMRR	Common Mode Rejection Ratio	$0V \leq V_{CM} \leq 12V$ $V^+ = 15V$	83	63 61	dB min
+PSRR	Positive Power Supply Rejection Ratio	$5V \leq V^+ \leq 15V$	83	63 61	dB min
-PSRR	Negative Power Supply Rejection Ratio	$0V \leq V^- \leq -10V$	94	74 73	dB min
V_{CM}	Input Common-Mode Voltage Range	$V^+ = 5V$ & $15V$ For CMRR ≥ 50 dB	-0.4	-0.1 0	V max
			$V^+ - 1.9$	$V^+ - 2.3$ $V^+ - 2.5$	V min
A_V	Large Signal Voltage Gain	$R_L = 100\text{ k}\Omega$ ⁽³⁾ Sinking Sourcing	1000	200 100	V/mV min
			500	90 40	V/mV min
		$R_L = 5\text{ k}\Omega$ ⁽³⁾ Sourcing Sinking	1000	100 75	V/mV min
			250	50 20	V/mV min
V_O	Output Voltage Swing	$V^+ = 5V$ $R_L = 100\text{ k}\Omega$ to $2.5V$	4.987	4.40 4.43	V min
			0.004	0.06 0.09	V max
		$V^+ = 5V$ $R_L = 5\text{ k}\Omega$ to $2.5V$	4.940	4.20 4.00	V min
			0.040	0.25 0.35	V max
		$V^+ = 15V$ $R_L = 100\text{ k}\Omega$ to $7.5V$	14.970	14.00 13.90	V min
			0.007	0.06 0.09	V max
		$V^+ = 15V$ $R_L = 5\text{ k}\Omega$ to $7.5V$	14.840	13.70 13.50	V min
			0.110	0.32 0.40	V max

(3) $V^+ = 15V$, $V_{CM} = 7.5V$, and R_L connected to $7.5V$. For Sourcing tests, $7.5V \leq V_O \leq 11.5V$. For Sinking tests, $2.5V \leq V_O \leq 7.5V$.

DC ELECTRICAL CHARACTERISTICS (continued)

The following specifications apply for $V^+ = 5V$, $V^- = 0V$, $V_{CM} = 1.5V$, $V_O = 2.5V$, and $R_L = 1M$ unless otherwise noted.

Boldface limits apply at the temperature extremes; all other limits $T_J = 25^\circ C$.

Symbol	Parameter	Conditions	Typical ⁽¹⁾	LMC6022I Limit ⁽²⁾	Units
I_O	Output Current	$V^+ = 5V$ Sourcing, $V_O = 0V$ Sinking, $V_O = 5V^{(4)}$	22	13 9	mA min
			21	13 9	mA min
		$V^+ = 15V$ Sourcing, $V_O = 0V$ Sinking, $V_O = 13V^{(5)}$	40	23 15	mA min
			39	23 15	mA min
I_S	Supply Current	Both Amplifiers $V_O = 1.5V$	86	140 165	μA max

(4) Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature and/or multiple Op Amp shorts can result in exceeding the maximum allowed junction temperature of $150^\circ C$. Output currents in excess of ± 30 mA over long term may adversely affect reliability.

(5) Do not connect output to V^+ when V^+ is greater than 13V or reliability may be adversely affected.

AC ELECTRICAL CHARACTERISTICS

The following specifications apply for $V^+ = 5V$, $V^- = 0V$, $V_{CM} = 1.5V$, $V_O = 2.5V$, and $R_L = 1M$ unless otherwise noted.

Boldface limits apply at the temperature extremes; all other limits $T_J = 25^\circ C$.

Symbol	Parameter	Conditions	Typical ⁽¹⁾	LMC6022I Limit ⁽²⁾	Units
SR	Slew Rate	See ⁽³⁾	0.11	0.05 0.03	V/ μs min
GBW	Gain-Bandwidth Product		0.35		MHz
Φ_M	Phase Margin		50		Deg
G_M	Gain Margin		17		dB
	Amp-to-Amp Isolation	See ⁽⁴⁾	130		dB
e_n	Input-Referred Voltage Noise	$F = 1$ kHz	42		nV/\sqrt{Hz}
i_n	Input-Referred Current Noise	$F = 1$ kHz	0.0002		pA/\sqrt{Hz}

(1) Typical values represent the most likely parametric norm.

(2) All limits are guaranteed by testing or correlation.

(3) $V^+ = 15V$. Connected as Voltage Follower with 10V step input. Number specified is the slower of the positive and negative slew rates.

(4) Input referred. $V^+ = 15V$ and $R_L = 100$ k Ω connected to 7.5V. Each amp excited in turn with 1 kHz to produce $V_O = 13$ V_{pp}.

TYPICAL PERFORMANCE CHARACTERISTICS

$V_S = \pm 7.5V$, $T_A = 25^\circ C$ unless otherwise specified

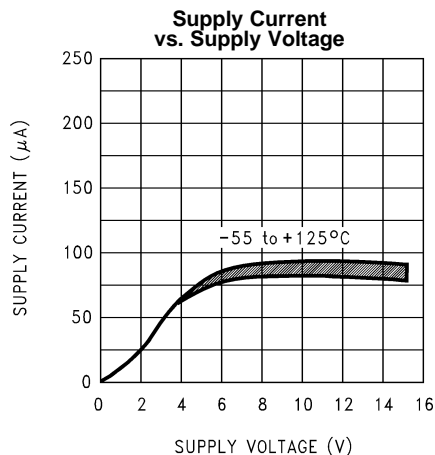


Figure 3.

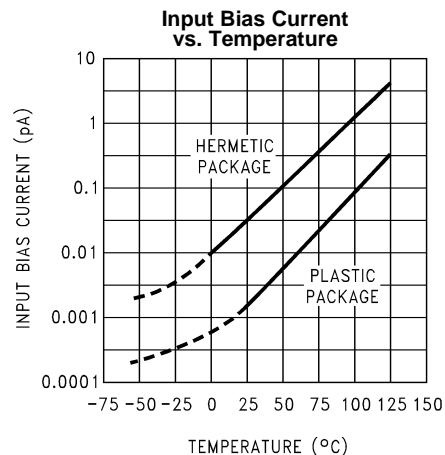


Figure 4.

Input Common-Mode Voltage Range vs. Temperature

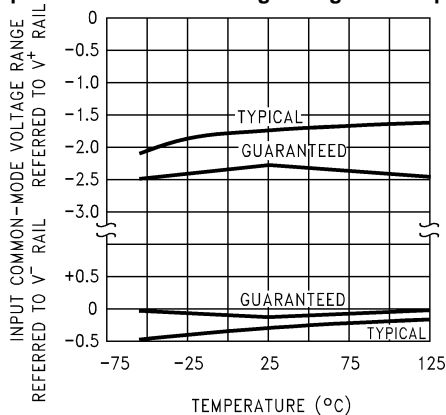


Figure 5.

Output Characteristics Current Sinking

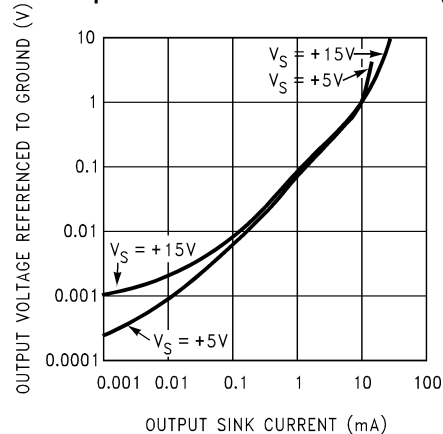


Figure 6.

Output Characteristics Current Sourcing

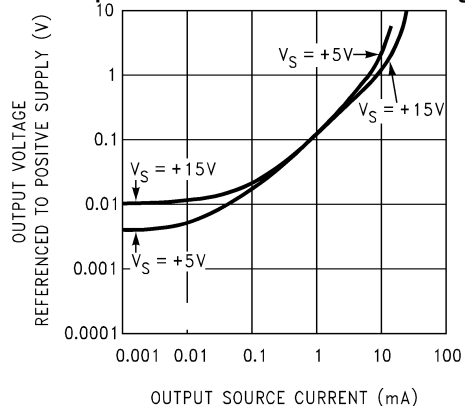


Figure 7.

Input Voltage Noise vs. Frequency

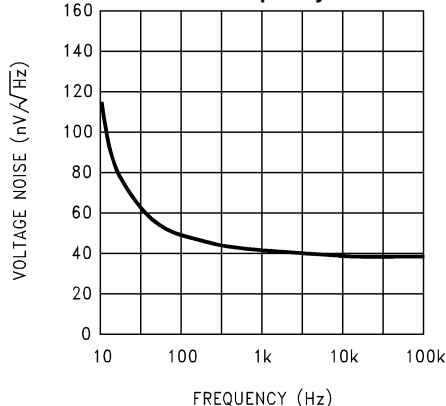
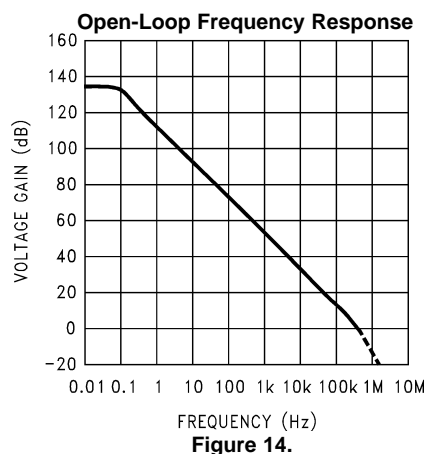
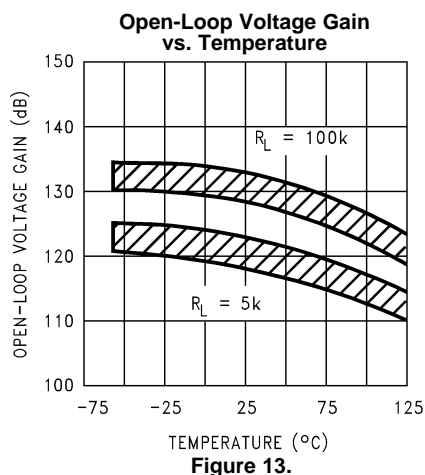
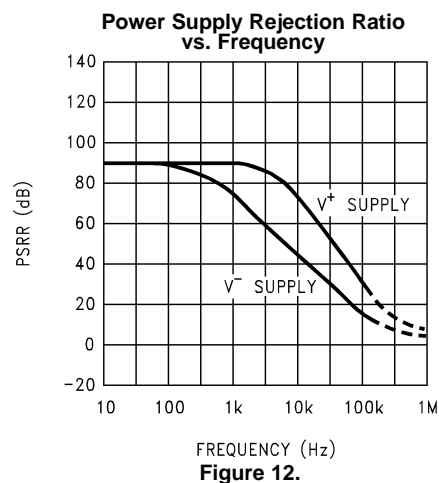
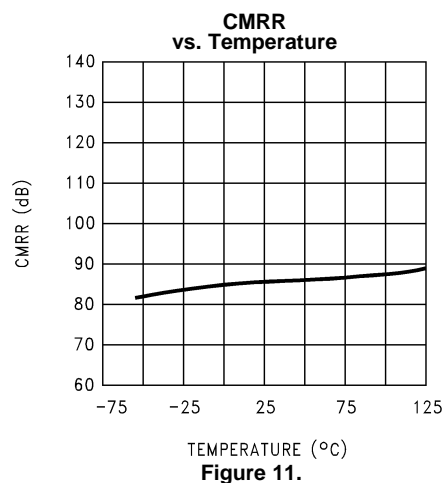
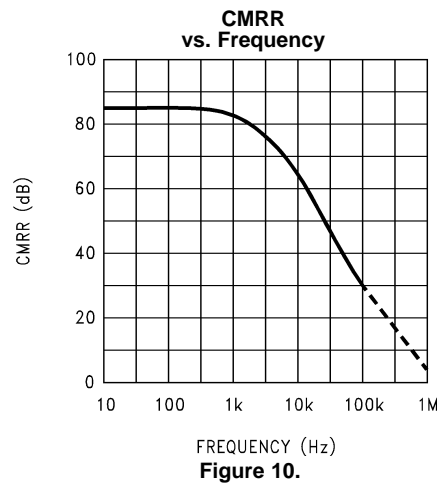
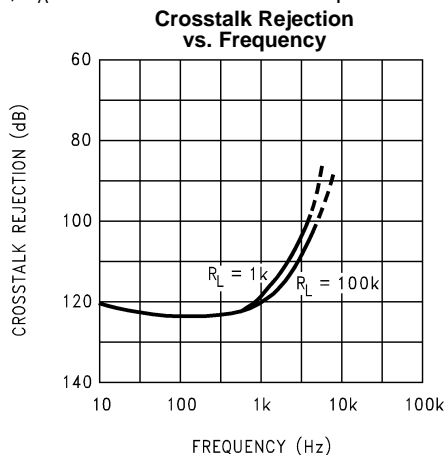


Figure 8.

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

$V_S = \pm 7.5V$, $T_A = 25^\circ C$ unless otherwise specified



TYPICAL PERFORMANCE CHARACTERISTICS (continued)

$V_S = \pm 7.5V$, $T_A = 25^\circ C$ unless otherwise specified

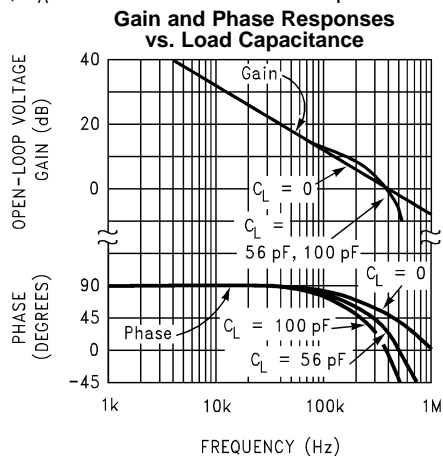


Figure 15.

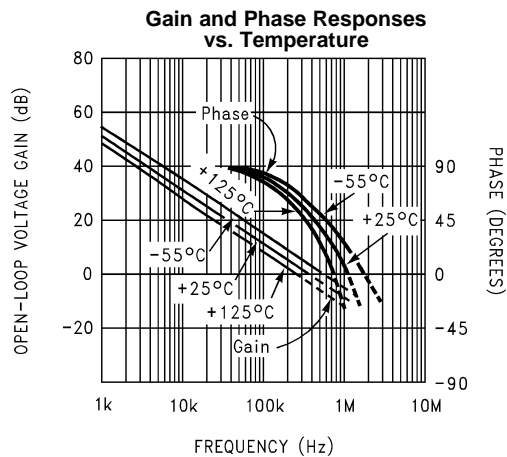


Figure 16.

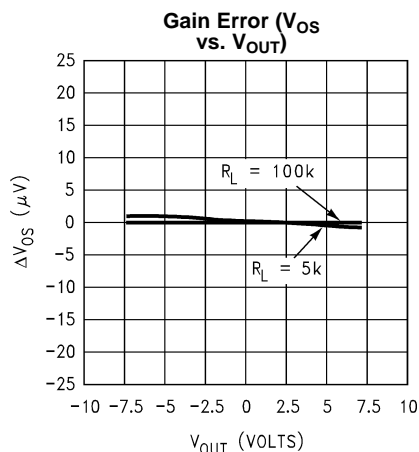


Figure 17.

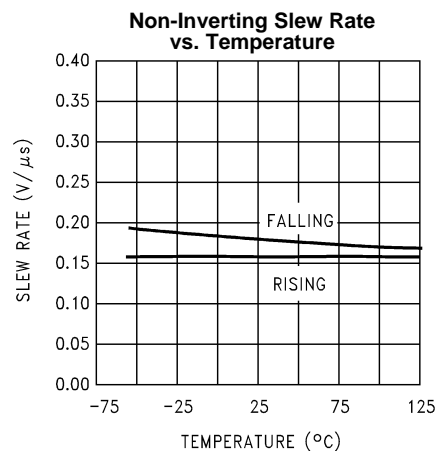


Figure 18.

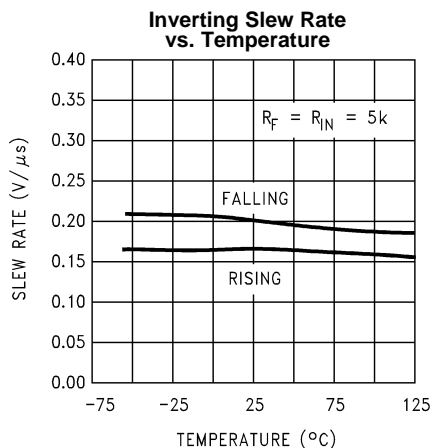


Figure 19.

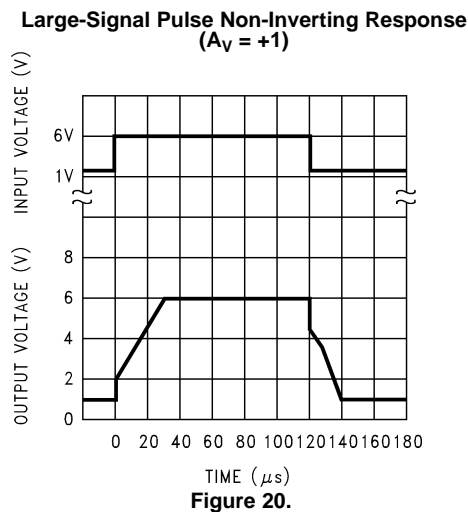


Figure 20.

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

$V_S = \pm 7.5V$, $T_A = 25^\circ C$ unless otherwise specified

Non-Inverting Small-Signal Pulse Response ($A_V = +1$)

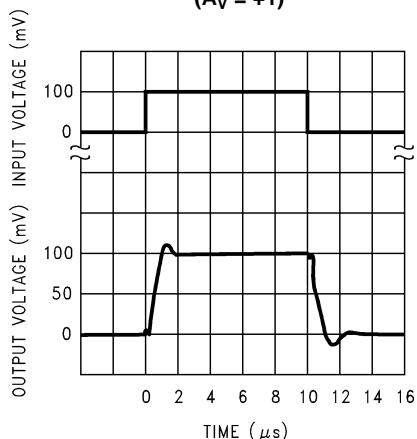


Figure 21.

Inverting Large-Signal Pulse Response

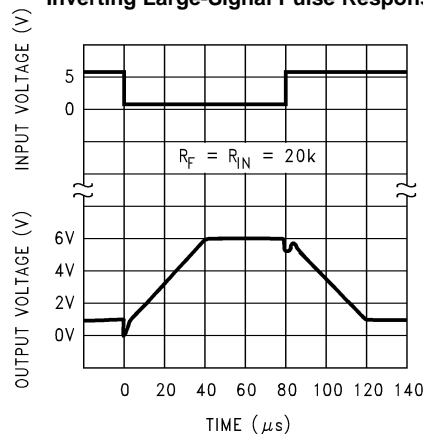


Figure 22.

Inverting Small-Signal Pulse Response

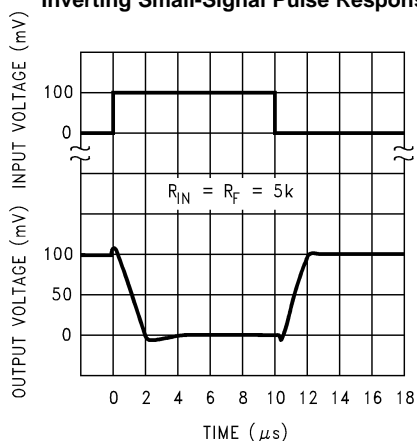
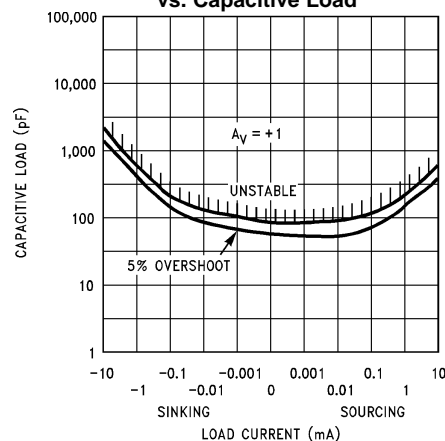


Figure 23.

Stability vs. Capacitive Load



Note: Avoid resistive loads of less than 500Ω, as they may cause instability.

Figure 24.

Stability vs. Capacitive Load

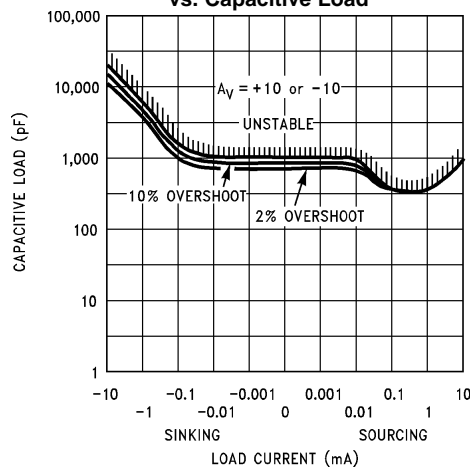


Figure 25.

APPLICATION HINTS

AMPLIFIER TOPOLOGY

The topology chosen for the LMC6022 is unconventional (compared to general-purpose op amps) in that the traditional unity-gain buffer output stage is not used; instead, the output is taken directly from the output of the integrator, to allow rail-to-rail output swing. Since the buffer traditionally delivers the power to the load, while maintaining high op amp gain and stability, and must withstand shorts to either rail, these tasks now fall to the integrator.

As a result of these demands, the integrator is a compound affair with an embedded gain stage that is doubly fed forward (via C_f and C_{ff}) by a dedicated unity-gain compensation driver. In addition, the output portion of the integrator is a push-pull configuration for delivering heavy loads. While sinking current the whole amplifier path consists of three gain stages with one stage fed forward, whereas while sourcing the path contains four gain stages with two fed forward.

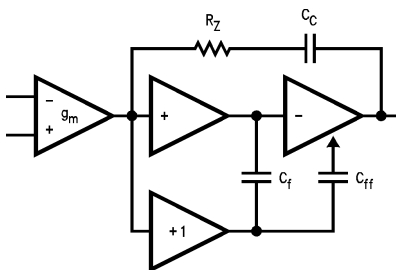


Figure 26. LMC6022 Circuit Topology (Each Amplifier)

The large signal voltage gain while sourcing is comparable to traditional bipolar op amps for load resistance of at least 5 k Ω . The gain while sinking is higher than most CMOS op amps, due to the additional gain stage; however, when driving load resistance of 5 k Ω or less, the gain will be reduced as indicated in the Electrical Characteristics. The op amp can drive load resistance as low as 500 Ω without instability.

COMPENSATING INPUT CAPACITANCE

Refer to the LMC660 or LMC662 datasheets to determine whether or not a feedback capacitor will be necessary for compensation and what the value of that capacitor would be.

CAPACITIVE LOAD TOLERANCE

Like many other op amps, the LMC6022 may oscillate when its applied load appears capacitive. The threshold of oscillation varies both with load and circuit gain. The configuration most sensitive to oscillation is a unity-gain follower. See the [TYPICAL PERFORMANCE CHARACTERISTICS](#).

The load capacitance interacts with the op amp's output resistance to create an additional pole. If this pole frequency is sufficiently low, it will degrade the op amp's phase margin so that the amplifier is no longer stable at low gains. The addition of a small resistor (50 Ω to 100 Ω) in series with the op amp's output, and a capacitor (5 pF to 10 pF) from inverting input to output pins, returns the phase margin to a safe value without interfering with lower-frequency circuit operation. Thus, larger values of capacitance can be tolerated without oscillation. Note that in all cases, the output will ring heavily when the load capacitance is near the threshold for oscillation.

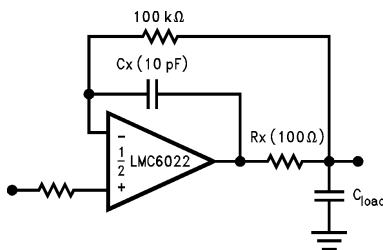


Figure 27. R_x , C_x Improve Capacitive Load Tolerance

Capacitive load driving capability is enhanced by using a pull up resistor to V^+ (Figure 28). Typically a pull up resistor conducting 50 μA or more will significantly improve capacitive load responses. The value of the pull up resistor must be determined based on the current sinking capability of the amplifier with respect to the desired output swing. Open loop gain of the amplifier can also be affected by the pull up resistor (see [Electrical Characteristics](#)).

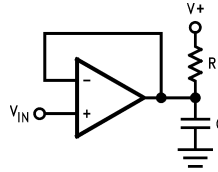


Figure 28. Compensating for Large Capacitive Loads with a Pull Up Resistor

PRINTED-CIRCUIT-BOARD LAYOUT FOR HIGH-IMPEDANCE WORK

It is generally recognized that any circuit which must operate with less than 1000 pA of leakage current requires special layout of the PC board. When one wishes to take advantage of the ultra-low bias current of the LMC6022, typically less than 0.04 pA, it is essential to have an excellent layout. Fortunately, the techniques for obtaining low leakages are quite simple. First, the user must not ignore the surface leakage of the PC board, even though it may sometimes appear acceptably low, because under conditions of high humidity or dust or contamination, the surface leakage will be appreciable.

To minimize the effect of any surface leakage, lay out a ring of foil completely surrounding the LMC6022's inputs and the terminals of capacitors, diodes, conductors, resistors, relay terminals, etc. connected to the op-amp's inputs. See Figure 29. To have a significant effect, guard rings should be placed on both the top and bottom of the PC board. This PC foil must then be connected to a voltage which is at the same voltage as the amplifier inputs, since no leakage current can flow between two points at the same potential. For example, a PC board trace-to-pad resistance of $10^{12}\Omega$, which is normally considered a very large resistance, could leak 5 pA if the trace were a 5V bus adjacent to the pad of an input. This would cause a 100 times degradation from the LMC6022's actual performance. However, if a guard ring is held within 5 mV of the inputs, then even a resistance of $10^{11}\Omega$ would cause only 0.05 pA of leakage current, or perhaps a minor (2:1) degradation of the amplifier's performance. See Figure 30a, Figure 30b, Figure 30c for typical connections of guard rings for standard op-amp configurations. If both inputs are active and at high impedance, the guard can be tied to ground and still provide some protection; see Figure 30d.

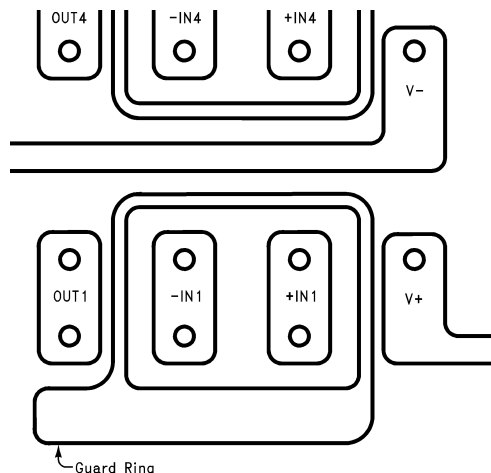
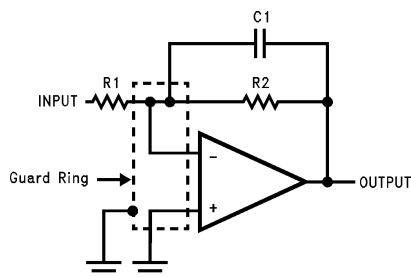
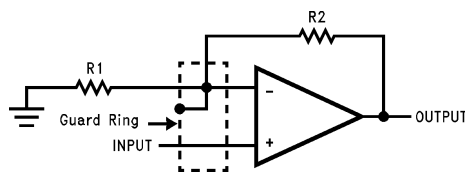


Figure 29. Example of Guard Ring in P.C. Board Layout (Using the LMC6024)

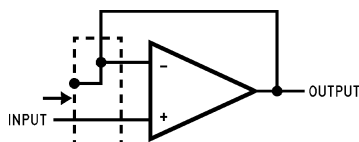
(a) Inverting Amplifier Guard Ring Connections



(b) Non-Inverting Amplifier Guard Ring Connections



(c) Follower Guard Ring Connections



(d) Howland Current Pump Guard Ring Connections

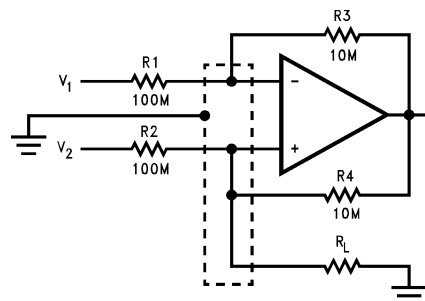
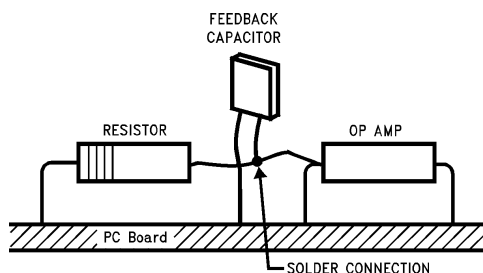


Figure 30. Guard Ring Connections

The designer should be aware that when it is inappropriate to lay out a PC board for the sake of just a few circuits, there is another technique which is even better than a guard ring on a PC board: Don't insert the amplifier's input pin into the board at all, but bend it up in the air and use only air as an insulator. Air is an excellent insulator. In this case you may have to forego some of the advantages of PC board construction, but the advantages are sometimes well worth the effort of using point-to-point up-in-the-air wiring. See [Figure 31](#).



(Input pins are lifted out of PC board and soldered directly to components. All other pins connected to PC board.)

Figure 31. Air Wiring

BIAS CURRENT TESTING

The test method of [Figure 32](#) is appropriate for bench-testing bias current with reasonable accuracy. To understand its operation, first close switch S2 momentarily. When S2 is opened, then

$$I^- = \frac{dV_{OUT}}{dt} \times C2. \quad (1)$$

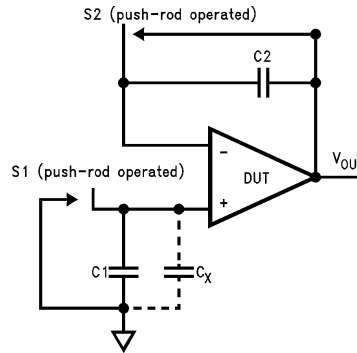


Figure 32. Simple Input Bias Current Test Circuit

A suitable capacitor for C2 would be a 5 pF or 10 pF silver mica, NPO ceramic, or air-dielectric. When determining the magnitude of I^- , the leakage of the capacitor and socket must be taken into account. Switch S2 should be left shorted most of the time, or else the dielectric absorption of the capacitor C2 could cause errors.

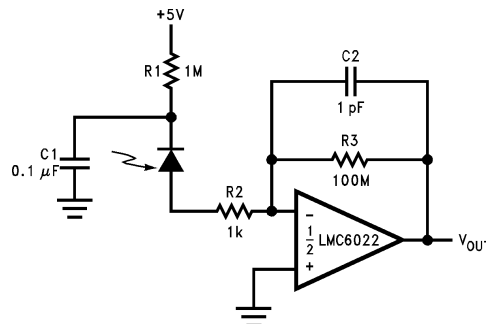
Similarly, if S1 is shorted momentarily (while leaving S2 shorted)

$$I^+ = \frac{dV_{OUT}}{dt} \times (C1 + C_x) \quad (2)$$

where C_x is the stray capacitance at the + input.

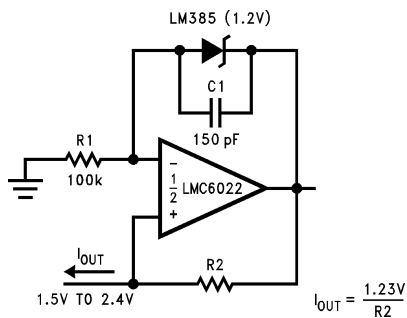
Typical Single-Supply Applications

($V^+ = 5.0 V_{DC}$)



Note: A 5V bias on the photodiode can cut its capacitance by a factor of 2 or 3, leading to improved response and lower noise. However, this bias on the photodiode will cause photodiode leakage (also known as its dark current).

Figure 33. Photodiode Current-to-Voltage Converter



(Upper limit of output range dictated by input common-mode range; lower limit dictated by minimum current requirement of LM385.)

Figure 34. Micropower Current Source

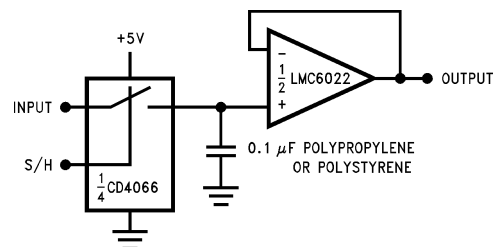
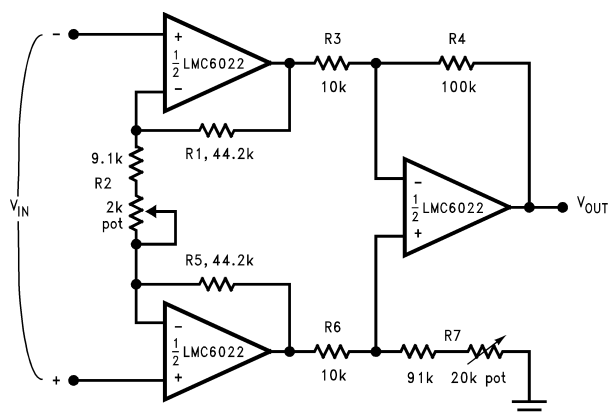


Figure 35. Low-Leakage Sample-and-Hold

(V+ = 5.0 V_{DC})



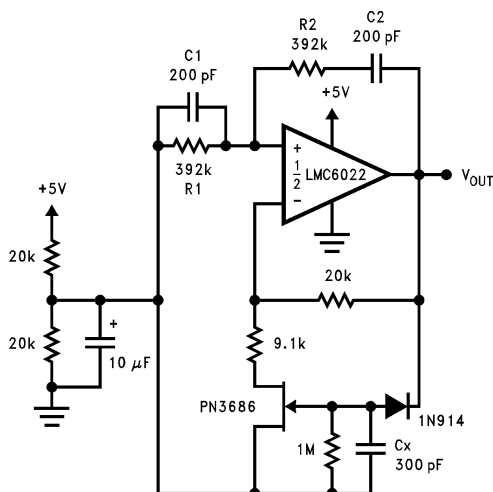
If R1 = R5, R3 = R6, and R4 = R7;

$$\text{Then } \frac{V_{OUT}}{V_{IN}} = \frac{R2 + 2R1}{R2} \times \frac{R4}{R3}$$

∴ A_V ≈ 100 for circuit shown

For good CMRR over temperature, low drift resistors should be used. Matching of R3 to R6 and R4 to R7 affects CMRR. Gain may be adjusted through R2. CMRR may be adjusted through R7.

Figure 36. Instrumentation Amplifier



Oscillator frequency is determined by R1, R2, C1, and C2:

$$f_{OSC} = 1/2\pi RC$$

where R = R1 = R2 and C = C1 = C2.

This circuit, as shown, oscillates at 2.0 kHz with a peak-to-peak output swing of 4.5V.

Figure 37. Sine-Wave Oscillator

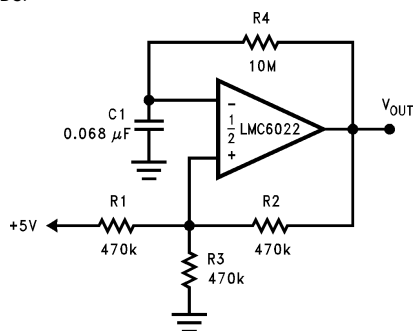
(V+ = 5.0 V_{DC})

Figure 38. 1 Hz Square-Wave Oscillator

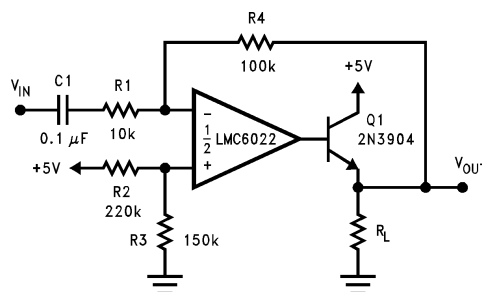
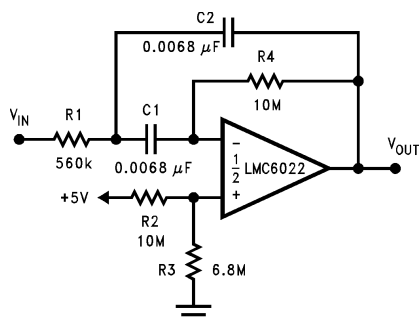
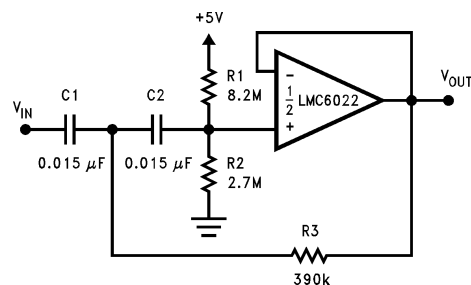


Figure 39. Power Amplifier



$f_o = 10$ Hz
 $Q = 2.1$
 Gain = -8.8

Figure 40. 10 Hz Bandpass Filter



$f_c = 10$ Hz
 $d = 0.895$
 Gain = 1

Figure 41. 10 Hz High-Pass Filter (2 dB Dip)

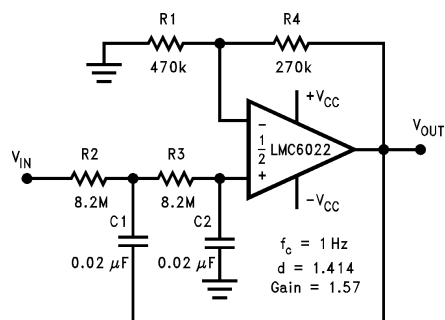
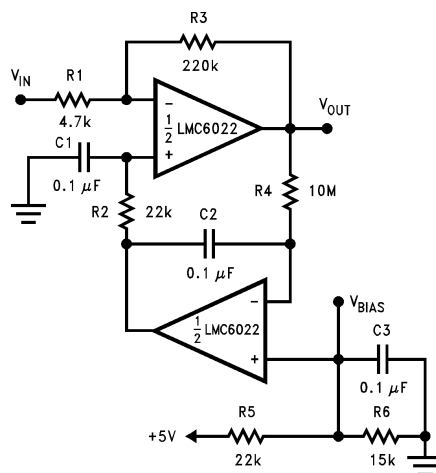


Figure 42. 1 Hz Low-Pass Filter (Maximally Flat, Dual Supply Only)

($V_+ = 5.0 V_{DC}$)



Gain = -46.8

Output offset voltage reduced to the level of the input offset voltage of the bottom amplifier (typically 1 mV), referred to V_{BIAS} .

Figure 43. High Gain Amplifier with Offset Voltage Reduction

REVISION HISTORY

Changes from Revision C (March 2013) to Revision D	Page
• Changed layout of National Data Sheet to TI format	15

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LMC6022IM/NOPB	Active	Production	SOIC (D) 8	95 TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LMC60 22IM
LMC6022IM/NOPB.A	Active	Production	SOIC (D) 8	95 TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LMC60 22IM
LMC6022IM/NOPB.B	Active	Production	SOIC (D) 8	95 TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LMC60 22IM
LMC6022IMX/NOPB	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LMC60 22IM
LMC6022IMX/NOPB.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LMC60 22IM
LMC6022IMX/NOPB.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LMC60 22IM

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMC6022IMX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMC6022IMX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0

TUBE

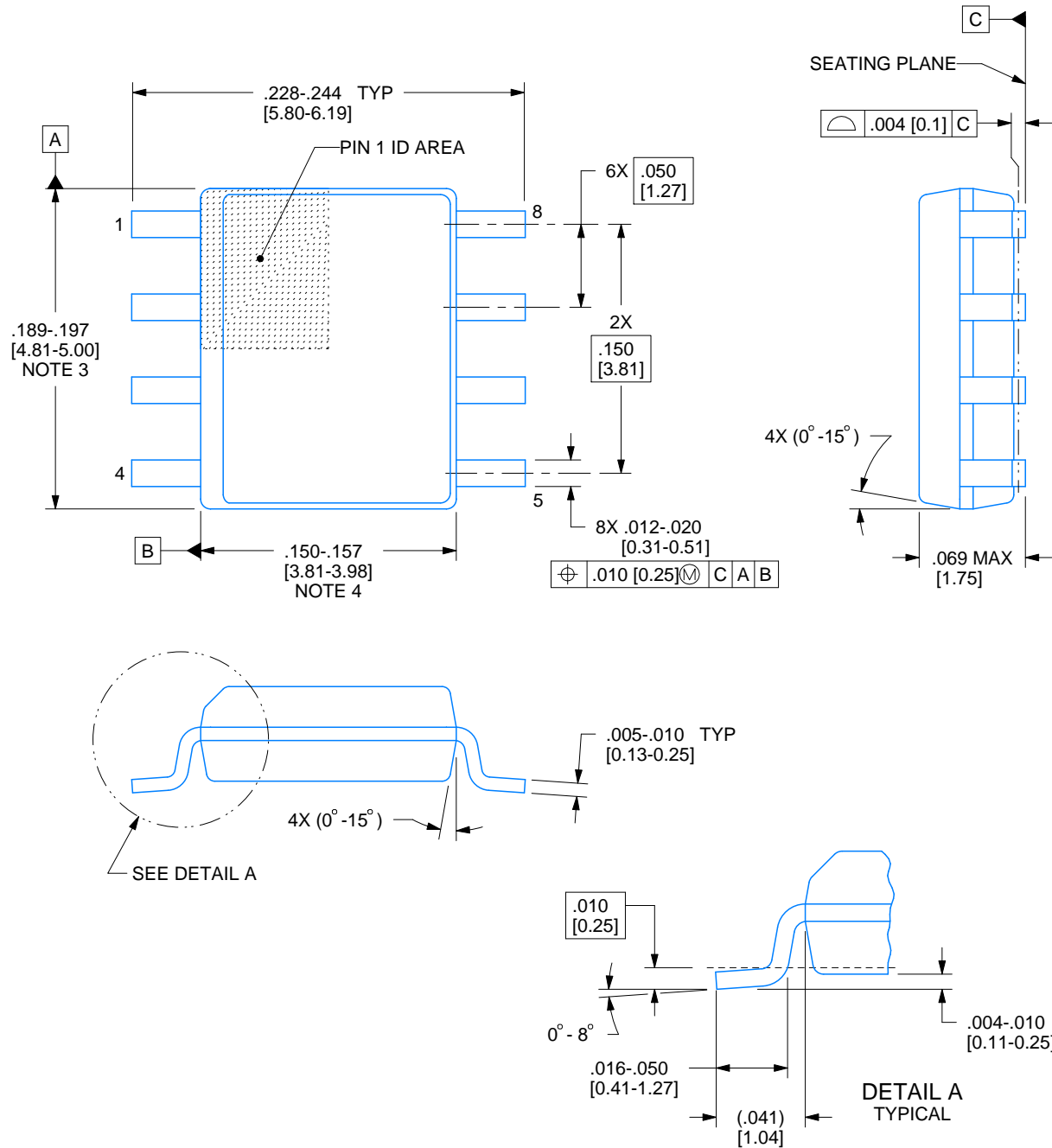


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
LMC6022IM/NOPB	D	SOIC	8	95	495	8	4064	3.05
LMC6022IM/NOPB.A	D	SOIC	8	95	495	8	4064	3.05
LMC6022IM/NOPB.B	D	SOIC	8	95	495	8	4064	3.05

D0008A**PACKAGE OUTLINE****SOIC - 1.75 mm max height**

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

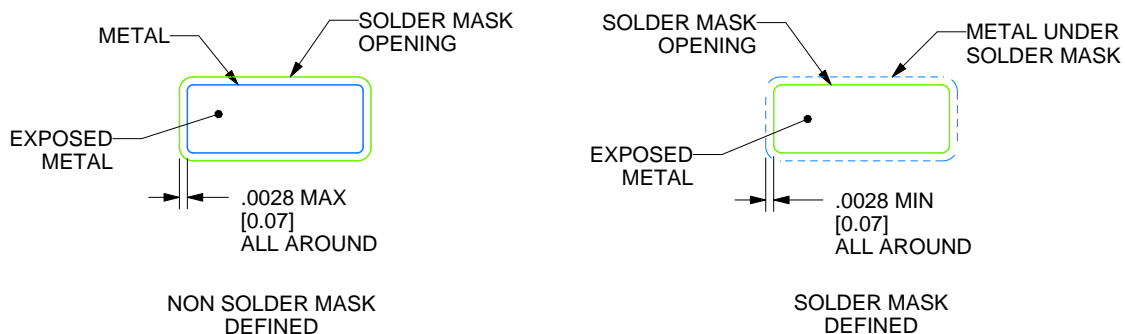
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed $.006$ [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



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NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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